

SANYO Semiconductors DATA SHEET

VEC2401— General-Purpose Switching Device Applications

Features

- The best suited for load switching applications.
- · Low ON-resistance.
- · Composite type facilitating high-density mounting.
- · 2.5V drive.
- Mounting high 0.75mm.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		4.5	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	18 A	
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm)1unit	0.9	W
Total Dissipation	PT	Mounted on a ceramic board (900mm ² X0.8mm)	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	0.5		1.3	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2.5A	4.5	7.5		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=2A, VGS=4V		32	42	$m\Omega$
	RDS(on)2	ID=1A, VGS=2.5V		40	57	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		570		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		110	·	pF
Reverse Transfer Capacitance	Crss	V _{DS} =10V, f=1MHz		80		pF

Marking: BG Continued on next page.

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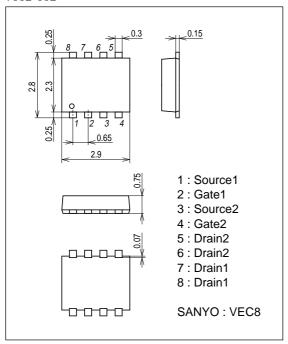
VEC2401

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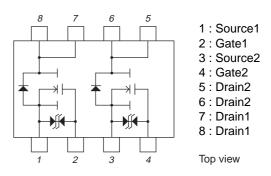
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Turn-ON Delay Time	td(on)	See specified Test Circuit.		15		ns
Rise Time	t _r	See specified Test Circuit.		105		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		50		ns
Fall Time	tf	See specified Test Circuit.		52		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4V, I _D =4.5A		7.6		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =4V, I _D =4.5A		1.2		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =4V, I _D =4.5A		2.1		nC
Diode Forward Voltage	V _{SD}	I _S =4.5A, V _{GS} =0V		0.85	1.2	V

Package Dimensions

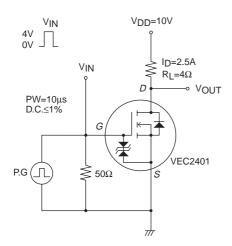
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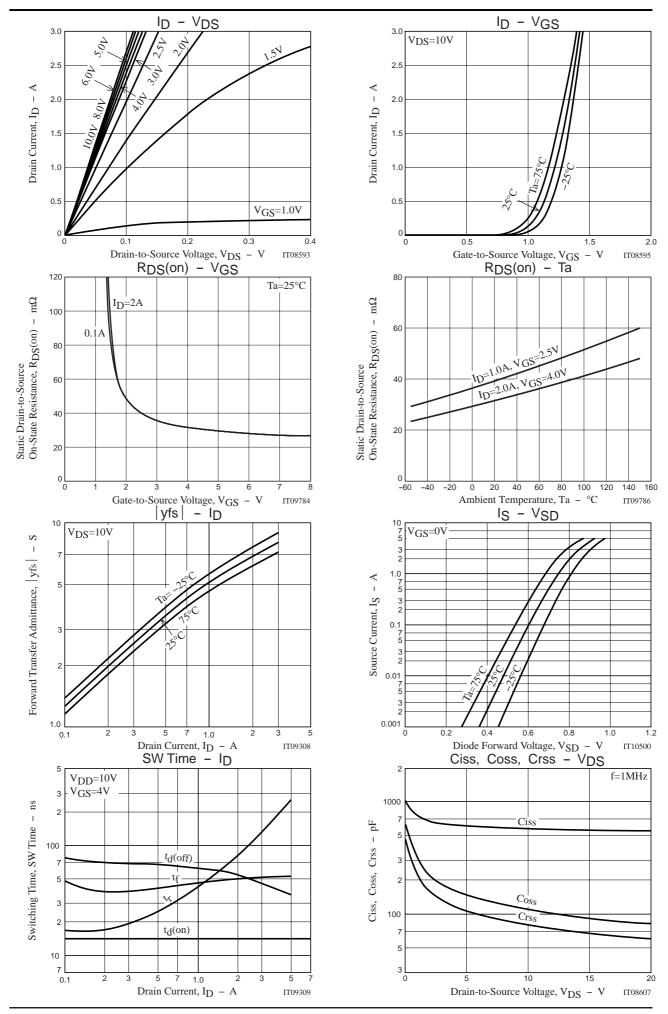


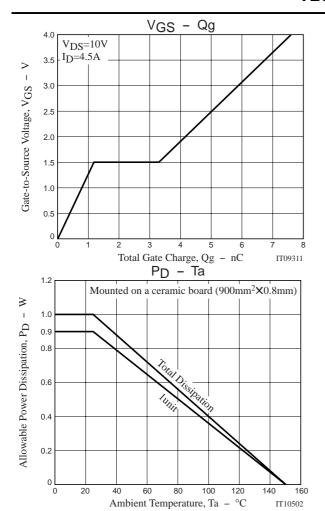
Electrical Connection

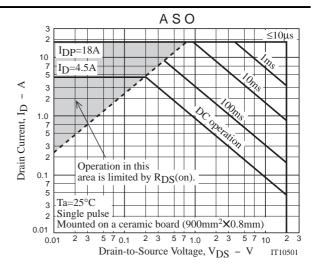


Switching Time Test Circuit









Note on usage: Since the VEC2401 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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